NSN 5961-01-374-8495

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-374-8495 **Inclosure Material:** Plastic **Overall Length:** Between 2.8 millimeters and 3.0 millimeters **Overall Height:** 1.1 millimeters **Overall Width:** Between 1.2 millimeters and 1.4 millimeters Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-23 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 22.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 200.00 milliamperes all primaries preset and 0.10 microamperes collector current, dc peak **Power Rating Per Characteristic:** 250.0 milliwatts any acceptable preset **Capacitance Rating In Picofarads:** Between 10.5 and 12.5 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No